

GC3202 - GC3208

POWER GENERATION Harmonics Generator Varactors

RoHS Compliant (e4)



www.MICROSEMI.com

DESCRIPTION

The GC3200 series of harmonic generator varactors uses a single epitaxial silicon die. Strict material and process controls result in high reproducibility. A unique silicon dioxide passivation process assures greater stability, reliability and low leakage currents at high temperatures. This series of diodes is available in a wide selection of capacitance values, breakdown voltages, transition times and cutoff frequencies for optimum circuit design. These devices have the best efficiencies and thermal dissipation available in single chip multiplier varactors.

Unless otherwise specified, capacitance will be within the range shown for each type. A capacitance tolerance of $\pm 10\%$ is available at an additional charge. Diodes can be optimized for custom electrical or mechanical specifications. Custom parameters for capacitance, voltage, transition time, cutoff frequency, etc. are available upon request.

All specifications shown above are based on the style 30 package, except for GC3202 and GC3203, which are based on the style 20 package. These latter two devices are available only in case styles 20 or 55 due to die size. Consult factory for availability.

A complete list of case styles available along with dimensions and package parasitics are available at <u>www.microsemi.com</u>. The cathode is the heat sink end of each package. Diode chips, alone or mounted on carriers with gold wire/ribbon leads are also available.

KEY FEATURES

- X2 Through X20 Harmonics Generation
- Excellent Efficiency
- High Output Power
- RoHS Compliant¹

¹ The GC3200 Series of products are supplied with a RoHS complaint Gold finish.

APPLICATIONS/BENEFITS

- Harmonics Generation
- Local Oscillators
- Frequency Synthesizers
- Up Converters

APPLICATIONS

The GC3200 series multiplier varactors can be used for all orders of multiplication from X2 through X20. They are used primarily in low harmonic order, high efficiency, high power applications. They are used in narrow and wide bandwidth frequency generator chains for all multiplication stages. Other applications include: voltage controlled oscillators, frequency synthesizers and up converters.

3202 - GC3208

IMPORTANT: For the most current data, consult our website: <u>www.MICROSEMI.com</u> Specifications are subject to change, consult the factory for further information.

These devices are ESD sensitive and must be handled using ESD precautions.

GC3202 - GC3208



POWER GENERATION Harmonics Generator Varactors

RoHS Compliant (e4)

CHIP ELECTRICAL PARAMETERS @ 25°C (unless otherwise specified)										
Model	Typ Output Freq. Range (GHz)	Typ Output Power (W)		V _b (V) I _R =10µA	C _j (pF) ¹ @-6V	F _C (GHz) ² @-6V	T _L (nS) ³	T _⊤ (pS)	θΡ ¹ (°C/W) ⁴	
Number		Р	MULT	(Min)	(Тур)	(Min)	(Min)	(Min)	(Max)	
GC3202	0.15 - 0.5	24	X3	180	18 – 25	20	400	8000	5	
GC3203	0.5 - 1.2	20	X3	80	8 – 12	60	200	1000	11	
GC3204	1.2 – 2.5	6	X4	80	3 – 6	110	200	650	20	
GC3205	2.5 – 5	2.5	X5	45	1.5 - 3	140	70	300	30	
GC3206	5 – 8	1.5	X2	40	1 - 2	150	35	150	40	
GC3207	8 – 12	1	X2	35	0.5 - 1.0	175	30	120	50	
GC3208	12 - 18	0.5	X2	25	0.3 – 0.6	200	15	100	75	

Notes:

s.
1. Junction Capacitance is measured at 1 MHz.
2. Cutoff frequency is calculated from: Fc-6 = 159 / (Cj ₋₆ Rs ₋₆)
3. Carrier Lifetime is measured @ I_F = 10mA , I_R = 6mA.
4. Thermal resistance is measure using pulsed conditions while measuring forward voltage drop across the diode mounted in an infinite heat sink

ABSOLUTE MAXIMUM RATINGS AT 25° C (UNLESS OTHERWISE SPECIFIED)										
Rating	Symbol	Value	Unit							
Maximum Leakage Current $@80\%$ of Minimum Rated V _B	I _R	20	nA							
Storage Temperature	T _{STG}	-65 to +150	°C							
Operating Temperature	T _{OP}	-55 to +125	°C							



GC3202 - GC3208

POWER GENERATION Harmonics Generator Varactors

RoHS Compliant (e4



Typical Package Options PACKAGE STYLE 00 **PACKAGE STYLE 20** - "D" 0.175"+-.015 TeCu 2 PLCS "A" ALUMINA TeCu 0.160"+-,010 DIA 2 PLCS R.038"+-.008 2 PÉCS "B" 0.093"+-.001 2 PLCS 0.231"+-:003 D A 0.030"MAX 0.150"+-.030 2 PLCS 0.779"+-.013 SILICON GOLD BACKING Notes: Dimensions vary by model number _ Consult factory for details Order as GC32xx - 00 PACKAGE STYLE 55 **PACKAGE STYLE 30** 0.119"/0.124" DIA 0.062"+-.002 DIA .010 MAX 2 PLS 0.232"+-.003 0.062"+-.002 KO VAR 0.027" MAX KOVAR 0.027"MAX 0.215"+-.010 ALUMINA 0.145" ALUMINA 0.062 +-.002 COPPER 0.040'+;.010 COPPER 0.062"+-.002 DIA Cp= .18 pF Lp= .42 nH 0.165"MAX -0.080"+-.003 DIA Cp= .50 pF Lp= .80 nH

OTHER PACKAGE STYLES AVAILABLE ON REQUEST CONSULT FACTORY

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Microchip: GC3204-150C